Jules Horowitz Reactor Project. 
Exploration tests concerning WIFI modules behaviour under gamma flux

S. Gaillot, B. Pouchin, J. G. Marques, I. López-Calle, F. J. Franco, and J. A. Agapito, Member IEEE

Abstract—Within the framework of experimental field on technologies developments for research reactors applications, an experimental program dedicated to electronics behaviour under flux has been performed on wireless (WIFI) modules. The interest of using the WIFI modules in an industrial facility is to limit and some cases to work without transmission lines between the experimental equipments in which sensors are embedded and the facility (i.e data acquisition room). The objectives of these tests were to determine the capabilities of WIFI modules to work in Nuclear Environment, to define the limitation due to the dose levels and to propose some adaptations in term of integration. These actions have been carried out on [2009-2010] period, in sharing collaboration between CEA (Commissariat à l’Energie Atomique et aux Energies Alternatives, France), ITN (Nuclear and Technological Institute, Portugal) and UCM (University Complutense of Madrid, Spain). The experimental program on WIFI modules took into account a first phase of data determination of dose levels based on Jules Horowitz Reactor environment. The second phase (performed by UCM and ITN) was dedicated to the selection of modules focused on commercial type (COTS approach). Then, irradiation tests of these modules using a $^{60}$Co source and in the RPI reactor have been performed by ITN with UCM. The results obtained are presented and discussed. As conclusion, some recommendations are given.

Index Terms—Electronics, WIFI Modules, COTS, Gamma flux, Dose tolerance.

I. INTRODUCTION

In a nuclear environment, the use of electronics is limited due to the doses effects on the components. In this context, some studies are performed in order to characterise the dose tolerance of electronics, and to propose some adaptations in order to increase the capability to work under flux.

The objective of this present work is to determine the dose tolerance of commercially available wireless (WIFI) modules (the so-called “Components Off The Shelf”, or COTS) in a nuclear environment, with gamma and neutron fluxes.

The results obtained about electronics dose tolerance was dedicated firstly for research reactor applications (embedded electronics on irradiation device) but it can be extended to other nuclear facilities in which the use of electronics WIFI modules could be interesting (process control instrumentation on circuits with dose levels constraints).

This work has been performed on 2009-2010 period in sharing collaboration between CEA in France (input data determination), UCM in Spain (modules selection, module preparation, expertise after tests) and ITN in Portugal (gamma irradiation facility, research reactor).

II. THE JHR FACILITY

The Jules Horowitz Reactor (JHR-Materials Testing Reactor) is under construction in the south of France (Cadarache, Bouches du Rhone). This Nuclear Facility is dedicated to perform irradiation of materials, fuels in support of present (LWR) and futures power plants (Gen. V, fusion). It allows also producing radioisotopes for medical applications, namely $^{99}$Mo. This facility will offer to the international community interesting irradiation capabilities (15 dpa/year at 100 MW) for core materials samples, high thermal neutron fluxes in the reflector for irradiation of fuels (corresponding to 8 times the neutron flux in a PWR). It will allow also a high flexibility in terms of experimental conditions, several irradiation locations in the core, in the reflector in fixed and also on movable locations (systems permitting to modify the distance between the sample and the core using pre-defined moving scenario). For different experimental issues, several thermal hydraulics conditions can be obtained (LWR (P&B), HTR, SFR...).

In addition, some supports utilities (storage pools, hot cells, non-destructive equipments (X rays, gamma imaging systems)) are integrated in the facility in order to propose to the customers a complete offer in terms of irradiation services.

III. NEUTRON FLUXES AND GAMMA DOSES EVALUATION IN THE JHR ENVIRONMENT

The irradiation devices which are embedded in the reactor (core and reflector) integrate different types of instrumentation permitting to follow on line the experimental parameters of the irradiation scenarios. These instrumentations can be classical (thermocouples, pressure gauges, flow meters) but can also be innovative (as cladding deformation sensors). Due to severe working constraints in the experimental devices (thermal-hydraulic conditions, gamma and neutron fluxes,
lack of place), specific developments had to be engaged to obtain satisfying results in terms of scientific data (ex. creep phenomenon determination on irradiated materials samples). Direct integration of electronics in the device can give some advantages as measuring close to the samples and consequently limiting the effect of long lines between the sensors and the instrumentation and control rooms.

Concerning the use of WIFI modules, other interests are identified as:

- Limiting the number of lines between the in-pile and out of pile parts
- Simplifying the operation constraints, connexions, deconnexions, under water line manipulations
- Increasing the autonomy of the device.

An important remark: note that the use of WIFI modules concerns now only sensors dedicated to experimental issues and not safety-related ones (reliability aspects difficult to demonstrate).

In all cases, some instrumentation which integrates electronics modules can be sensible to neutron and gamma fluxes. Some verifications of behaviour under flux have to be performed prior to their use in order to define their limitation in terms of doses.

The first phase in this work was to estimate the dose levels in a research reactor in different zones where the electronic modules can be located. These doses viewed by the electronics can be due to relative short distance to the reactor core but also due to operation scenario (i.e., consequence of unloading an irradiated device from the core). This operation performed closed to the other devices in the reactor can affect the behaviour of electronics located in their head (i.e., upper part of the device).

### A. Neutron flux evaluation

The calculations performed showed that the neutron effects become negligible in an external zone around the core higher than 2 m. Electronics modules located in the head of the devices are in normal conditions not affected by the neutron flux.

### B. Gamma dose evaluation

Fig. 2 gives the gamma dose calculation distribution (Gy/h) along the axis (m) and compare the results to OSIRIS French reactor in the same conditions.

GRDR Gamma Rays Dose Rates normalised to 100 MW fit very well with OSIRIS and JHR. In the region from the top of the core to 5-m above, GRDR decreases approximately by a factor 10 each metre.

### IV. DESCRIPTION OF IRRADIATION REQUIREMENTS

The physical values measured on the experimental loops (in-pile part) in the reactor pool are obtained via measurement chains between the transducer and data acquisition system.

The generic functions of an embedded measuring chain are recalled in Table IV. Besides, Table IV recalls the irradiation requirements for possible embedded electronic equipments in the JHR reactor pool.

### V. WIFI MODULES EXPERIMENTAL TESTS

#### A. Reminder of the context

During the period [2006 to 2009], the FP6 Integrated Infrastructure Initiative MTR+I3 permitted to create a community on
TABLE II
IRRADIATION LEVEL ESTIMATION IN JHR CORE ENVIRONMENT.

<table>
<thead>
<tr>
<th>Description</th>
<th>Location</th>
<th>Type</th>
<th>Instantaneous gamma irradiation level</th>
<th>Integrated gamma irradiation level</th>
<th>Neutron irradiation level</th>
</tr>
</thead>
<tbody>
<tr>
<td>Sensors (transducer + integrated electronic system)</td>
<td>Device extension</td>
<td>P&amp;N Sensors</td>
<td>0.3 Gy/h</td>
<td>13 kGy</td>
<td>Minor</td>
</tr>
<tr>
<td>Digital TC multiplexers Measurement multiplexers on power cables</td>
<td>Device extension</td>
<td>To be defined</td>
<td>0.3 Gy/h</td>
<td>13 kGy</td>
<td>Minor</td>
</tr>
<tr>
<td>Wireless WIFI connection module</td>
<td>Device extension</td>
<td>Industrial type</td>
<td>0.3 Gy/h</td>
<td>13 kGy</td>
<td>Minor</td>
</tr>
<tr>
<td>Mobile source in front of embedded electronic equipment (*)</td>
<td>Head/Device</td>
<td>WIFI Modules, Multiplexers, sensors</td>
<td>6.4 Gy/h</td>
<td>106 Gy</td>
<td>To be specified</td>
</tr>
</tbody>
</table>

(*) Hypothesis: 1-minute exposure, 20-cm water layer between the source and electronic system.

Material Testing Reactors representing 18 countries [1]. One action of this program concerned the behaviour of electronics under radiation. This action was shared between CEA in France and ITN in Portugal. UCM in Spain was associated to this action due to relevant feedback about previous work performed with ITN on electronics for CERN applications. In this context, tests on behaviour on WIFI modules under flux have been identified for experimental data transmission because of innovative technique in Nuclear environment.

VI. WIFI MODULES SELECTION

The most complete suite of WIFI technology solutions available in the industry are distributed in function of the transmission radio-frequency. The ISM frequencies (Industrial, Scientific and Medical) are bands reserved internationally for non-commercial purposes. The highest frequency of ISM bands is 2.4 GHz. The ISM bands are generally used and the higher the frequency the more tolerant is the device, therefore 2.4 GHz is the band chosen for the radio-frequency of the wireless device under test. Two types of modules called M1 & M2\(^1\) offer solutions for 2.4-GHz band. They have been selected for these tests.

The demonstration kit from M1 is a good candidate for the irradiations because the microprocessor and other elements are fitted separated from the radio-frequency (RF) module and it would be easier to find the radiation tolerance of each component separately. Also, in order to test a wireless transmission device from another manufacturer on the market and to compare their behavior under irradiation, a demonstration kit from M2 is chosen because of the high integration level that includes in the same chip the microprocessor, RF transceiver module and the flash memory. All these components are built in CMOS technologies.

Therefore, the possible damage induced by displacement is negligible since CMOS devices are majority carriers devices. However, it is well-known their sensitivity to ionising dose. Gamma or X rays and charged ions are liable to create electron-hole pairs that can be eventually trapped in the SiO\(_2\) layer leading to a MOSFET threshold voltage shift and the appearance of large leakage currents.

From the whole set of devices, the most sensitive device is the internal microprocessor. Although the scale of the CMOS technology is unknown, due to the large amount of gates and other circuits, its complexity is great and the integration high. Thus this device is the most sensitive to gamma radiation.

Other devices are the crystal oscillators. According to the literature, these are insensitive to permanent damage due to ionizing radiation. Indeed, transient changes of the resonance frequency are usually related to small temperature growth rather than the appearance of photoelectric currents.

Finally, other CMOS devices such as multiplexers, amplifiers and or gates are also affected by the radiation. However, these devices do not need a large scale of integration due to the low number of necessary transistors. Therefore, problematic issues such as the presence of leakage currents are not liable to occur making the devices more tolerant to the ionizing radiation.

A. Experimental tests performed with \(^{60}\text{Co}\) source and RPI reactor at ITN

The Portuguese Research Reactor (RPI) is a 1-MW pool-type reactor, operating since 1961. A fast neutron irradiation facility was built at the RPI to test commercial electronic components for CERN within a program started in 1999 [2]. This facility currently allows irradiating electronic modules with fast neutron fluxes (E > 1 MeV) up to 4·10\(^8\) n/cm\(^2\)/s; the simultaneous gamma dose rate is up to 60 Gy/h. Complementary irradiations were performed in an industrial \(^{60}\text{Co}\) source, allowing gamma dose rates up to 10 kGy/h. WIFI modules were irradiated in a secondary irradiation position, at a gamma dose rate of approximately 200 Gy/h.

\(^{1}\)M1, M2 correspond to commercial modules types. For more precise information, contact the authors.
**B. Results**

The different tests performed on WIFI modules under neutron and/or gamma radiation gave the results summarized in Table VI-B.

The results of the tests for the M1 and M2 modules show that the microprocessor (or acquisition module) is the most sensitive component of the entire device and fail after 500 Gy (@300Gy/h) in both cases. The results also show that the RF transceiver module (M1) is more tolerant to the radiation and continues to run after 3.8 kGy (@300Gy/h). The final conclusions is that M1 shows better performance and it is necessary to use shielding data acquisition module separated from the RF module.

Other exploratory tests were done with Pt-100 temperature sensors from M3. These temperature sensors, not intended for applications under radiation, use XBEE RF modules. The sensors were irradiated in the RPI with a neutron fluence of $4 \times 10^{12}$ n/cm$^2$ and a gamma dose of 210 Gy without any degradation. While the neutron fluence exceeded the necessary for the tests for the JHR, the gamma dose was too low; therefore sensors were also irradiated in the $^{60}$Co source of ITN. A clear degradation of the in-board power supplies was visible after 200 Gy and the devices ceased working after approximately 600 Gy. The RF modules were also irradiated without power being applied and showed a better radiation behaviour: after 1 kGy, the XBEE modules were still operational but failed after 2 kGy.

**C. Recommendations**

Using these results, several recommendations have been proposed based on feedback issued on these WIFI gamma tolerance tests and are included in Table VI-C.

From the results obtained from this work on WIFI modules gamma tolerance tests, some proposals have been performed on a possible application concerning materials irradiation capsule embedded in a material testing reactor.

The WIFI module (transmitter) is to be located on the head of the capsule transfers data (e.g., temperature sensors) up to out of pile part (receiver).

The gamma tolerance results obliged to remove the acquisition cards from the core and to shield it. Nevertheless, some electrical lines (supper standard lines-serial type) are necessary (but limited) between the out of pile and in pile part in order to drive the electronic card as described below:

1) Line for power supply.
2) Lines for transmission protocol.
3) Line for ground.

Finally, a test of location RF transmitter in the water versus depth has also to be checked in order to determine the lower acceptable level for correct transmission.

**VII. Conclusions and Perspectives**

This experimental work shared between CEA, ITN and UCM allow exploring the WIFI modules behaviour under flux. The first results obtained based from COTS approach indicate that the Radio Frequency (RF) module is well resistant (gamma source up to 3.5 kGy). Nevertheless, the acquisition
TABLE IV
RECOMMENDATIONS ABOUT WIFI MODULES USE.

<table>
<thead>
<tr>
<th>Item</th>
<th>Type</th>
<th>Recommendations</th>
</tr>
</thead>
<tbody>
<tr>
<td>Electronic Components</td>
<td>RF module</td>
<td>Prefer module working at high frequency (ex: ISM 2.4 GHz).</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Gamma tolerance higher than 3.5 kGy.</td>
</tr>
<tr>
<td>Multiplexer</td>
<td>Tolerant</td>
<td>to gamma irradiation</td>
</tr>
<tr>
<td>Acquisition module</td>
<td>Gamma</td>
<td>tolerance lower (500 Gy) critical components:</td>
</tr>
<tr>
<td></td>
<td>module</td>
<td>microprocessor &amp; controller</td>
</tr>
<tr>
<td></td>
<td></td>
<td>➔ Prefer protected location &amp; foreseen shielding.</td>
</tr>
<tr>
<td>Flash RAM</td>
<td>Prefer CMOS technology which is more tolerant to neutrons</td>
<td></td>
</tr>
<tr>
<td>Voltage regulator</td>
<td>Prefer to work without it (sometimes, it is necessary for microprocessor work in stable conditions)</td>
<td></td>
</tr>
</tbody>
</table>

Another option would be to locate electronics boards far from the gamma sources in order to limit gamma impacting doses.

A final remark: Requirements for shielding depending on the dose level, for ordinary components, can be taken up from Table VII.

From the characteristics given before, we can deduce the shielding thickness that would lead to an acceptable integrated dose (100 Gy) on electronics boards as those of Table VII.

As conclusion of this exploration tests on WIFI modules, their use in a research reactor environment induce a strong expertise of the electronics components which can impose some adaptations (choice of specific technology as CMOS, shielding or distance increase from the gamma sources).

Nevertheless, the use of WIFI module can be interesting in an industrial facility for wireless information transfer from a sensor located in a circuit (as flow meter, pressure sensor, level sensors).

REFERENCES
